NSN 5961-01-235-8774

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-235-8774 **Inclosure Material:** Ceramic **Overall Length:** Between 0.800 inches and 0.840 inches **Overall Diameter:** Between 0.292 inches and 0.296 inches **Mounting Method:** Press fit **Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.9 forward voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 ferrule and 1 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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